Vishay High Power Products

## **Medium Power** Silicon Rectifier Diodes, 12 A

#### **FEATURES**

- Voltage ratings from 50 to 1000 V
- High surge capability
- · Low thermal impedance
- · High temperature rating
- · Can be supplied as JAN and JAN-TX devices in accordance with MIL-S-19500/260
- · RoHS compliant

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I <sub>F(AV)</sub>		12 <sup>(1)</sup>	А		
	T <sub>C</sub>	150 <sup>(1)</sup>	°C		
I <sub>FSM</sub>	50 Hz	230	- A		
	60 Hz	240 (1)			
l <sup>2</sup> t	50 Hz	260	– A²s		
	60 Hz	240			
T <sub>C</sub>		- 65 to 200	°C		
V <sub>RRM</sub>	Range	50 to 1000 <sup>(1)</sup>	V		

#### Note

<sup>(1)</sup> JEDEC registered values

**PRODUCT SUMMARY** 

I<sub>F(AV)</sub>

#### **ELECTRICAL SPECIFICATIONS**

TYPE NUMBER <sup>(2)</sup>	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>R(RMS)</sub> , MAXIMUM RMS REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RM</sub> , MAXIMUM DIRECT REVERSE VOLTAGE V T <sub>C</sub> = - 65 °C TO 200 °C	
	T <sub>C</sub> = - 65 °C TO 200 °C	T <sub>C</sub> = - 65 °C TO 200 °C	T <sub>C</sub> = - 65 °C TO 200 °C		
1N1199A	50 <sup>(1)</sup>	35 <sup>(1)</sup>	100 (1)	50 <sup>(1)</sup>	
1N1200A	100 (1)	70 (1)	200 (1)	100 (1)	
1N1201A	150 <sup>(1)</sup>	105 <sup>(1)</sup>	300 (1)	150 <sup>(1)</sup>	
1N1202A	200 (1)	140 <sup>(1)</sup>	350 (1)	200 (1)	
1N1203A	300 (1)	210 (1)	450 <sup>(1)</sup>	300 (1)	
1N1204A	400 (1)	280 (1)	600 (1)	400 (1)	
1N1205A	500 <sup>(1)</sup>	350 (1)	700 (1)	500 <sup>(1)</sup>	
1N1206A	600 (1)	420 (1)	800 (1)	600 (1)	
1N3670A	700 (1)	490	900 (1)	700 (1)	
1N3671A	800 (1)	560	1000 (1)	800 (1)	
1N3672A	900 (1)	630	1100 (1)	900 (1)	
1N3673A	1000 (1)	700	1200 (1)	1000 (1)	

#### Notes

(1) JEDEC registered values

<sup>(2)</sup> Basic part number indicates cathode to case; for anode to case, add "R" to part number, e.g., 1N1199RA



DO-203AA (DO-4)

12 A



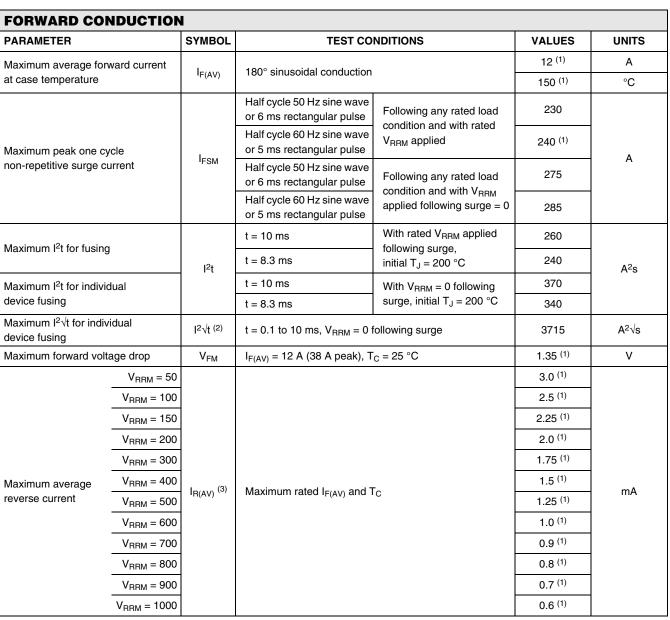




## 1N1...A, 1N36..A Series

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Notes

<sup>(1)</sup> JEDEC registered values

<sup>(2)</sup> I<sup>2</sup>t for time  $t_x = I^2 \sqrt{t} x \sqrt{t_x}$ 

<sup>(3)</sup> Maximum peak reverse current ( $I_{RM}$ ) under same conditions  $\approx 2 \text{ x rated } I_{R(AV)}$ 



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating case and storage temperature range		T <sub>C</sub> , T <sub>Stg</sub>		- 65 to 200 <sup>(1)</sup>	°C	
Maximum internal thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	2.0 (1)	°C/W	
Thermal resistance, case to sink		R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.5	0/00	
Mounting torque	minimum			1.36 (12)	N ⋅ m (lbf ⋅ in)	
	maximum		Torque applied to nut; non-lubricated threads	1.69 (15)		
	minimum		Targue applied to put lubricated threads	1.07 (9.45)		
	maximum		Torque applied to nut; lubricated threads	1.30 (11.55)		
	minimum		Torque applied to device encoulubricated threads	1.17 (10.35)		
	maximum		Torque applied to device case; lubricated threads	1.43 (12.65)		
Approximate weight				7.0	g	
				0.25	oz.	
Case style			JEDEC	DO-203AA (DO-4)		

Note

(1) JEDEC registered values

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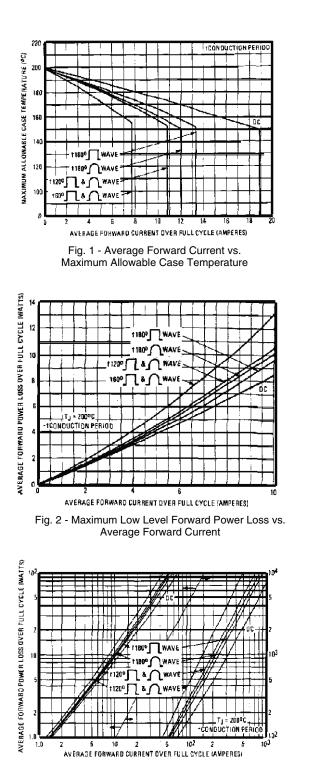
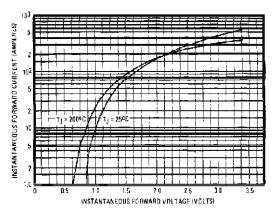


Fig. 3 - Maximum High Level Forward Power Loss vs. Average Forward Current



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Fig. 4 - Maximum Forward Voltage vs. Forward Current

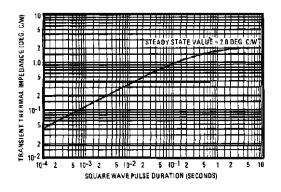
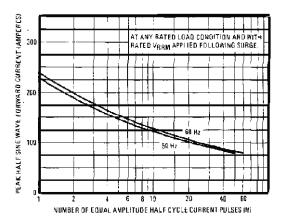
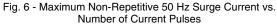


Fig. 5 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration





LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95311	
Dimensions	nttp://www.visnay.com/doc?95311	

www.vishay.com 4 For technical questions, contact: ind-modules@vishay.com

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